



US 20100148163A1

(19) **United States**

(12) **Patent Application Publication**
Im et al.

(10) **Pub. No.: US 2010/0148163 A1**
(43) **Pub. Date: Jun. 17, 2010**

(54) **ORGANIC LIGHT EMITTING DISPLAY APPARATUS**

(22) Filed: **Dec. 11, 2009**

(76) Inventors: **Ki-Ju Im**, Suwon-si (KR);
Yong-Sung Park, Suwon-si (KR);
Yong-Woo Park, Suwon-si (KR);
Moo-Jin Kim, Suwon-si (KR);
Han-Hee Yoon, Suwon-si (KR);
Kwang-Hae Kim, Suwon-si (KR);
Sung-Won Doh, Suwon-si (KR);
Kyoung-Bo Kim, Suwon-si (KR);
Gun-Shik Kim, Suwon-si (KR);
Jun-Sik Oh, Suwon-si (KR)

(30) **Foreign Application Priority Data**

Dec. 11, 2008 (KR) 10-2008-0125962

Publication Classification

(51) **Int. Cl.**
H01L 51/50 (2006.01)
(52) **U.S. Cl.** **257/40; 257/59; 257/72; 257/88;**
257/E51.022

Correspondence Address:
CHRISTIE, PARKER & HALE, LLP
PO BOX 7068
PASADENA, CA 91109-7068 (US)

(57) **ABSTRACT**

An organic light emitting display apparatus includes an organic light emitting diode, a photo sensor, and a light blocking portion. The light blocking portion is at at least a side of the photo sensor so that light emitted from the organic light emitting diode is not directly incident on the photo sensor.

(21) Appl. No.: **12/636,303**

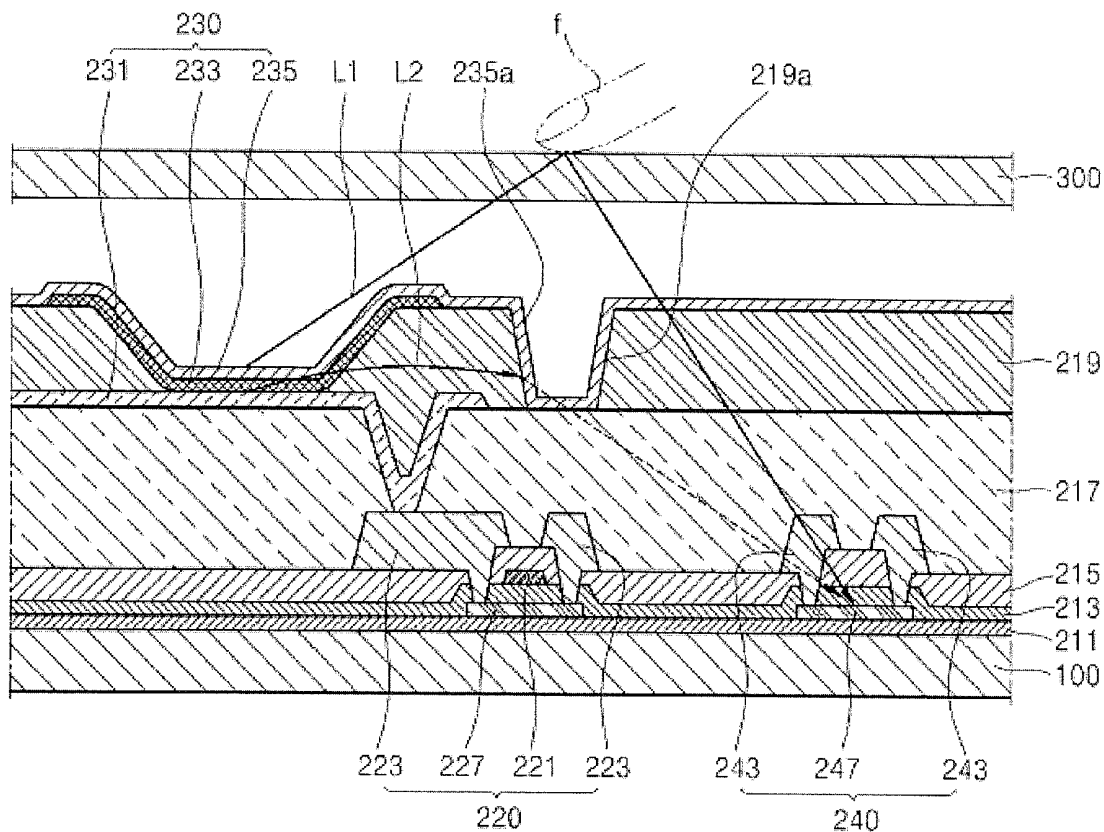


FIG. 1

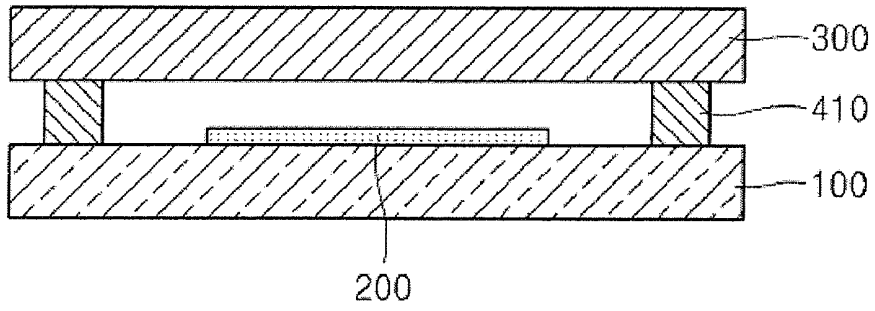


FIG. 2

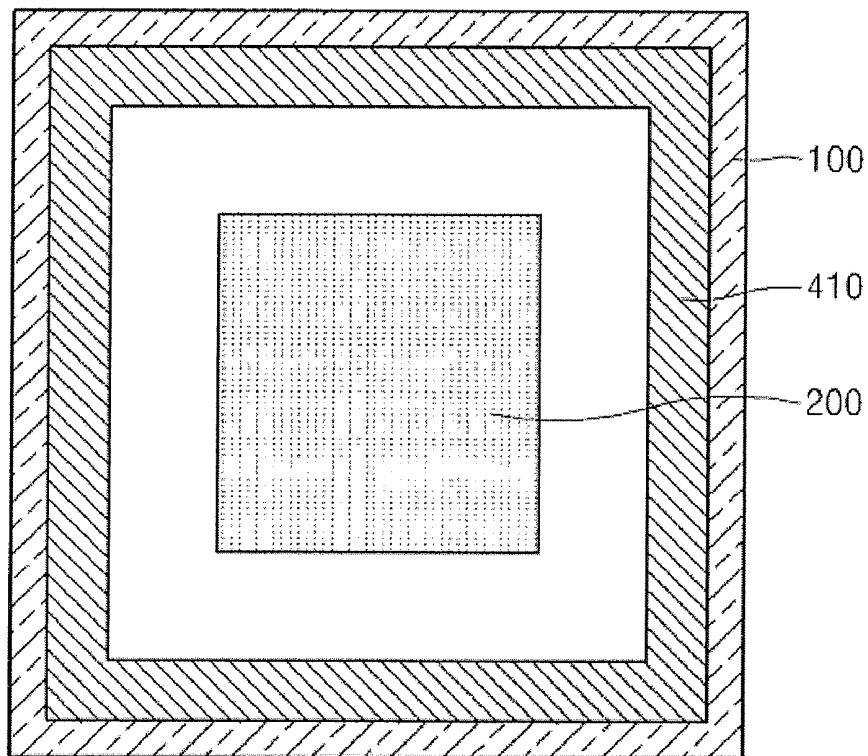


FIG. 3

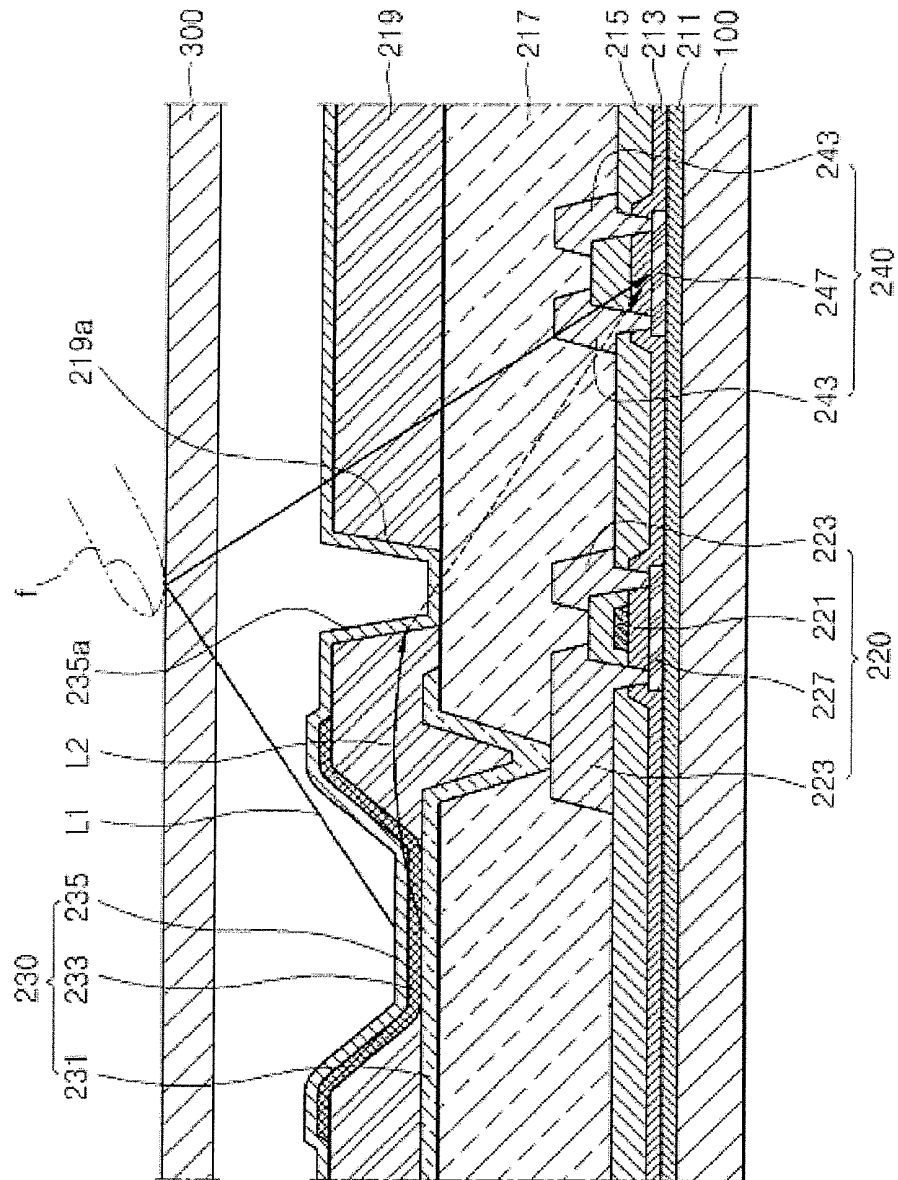
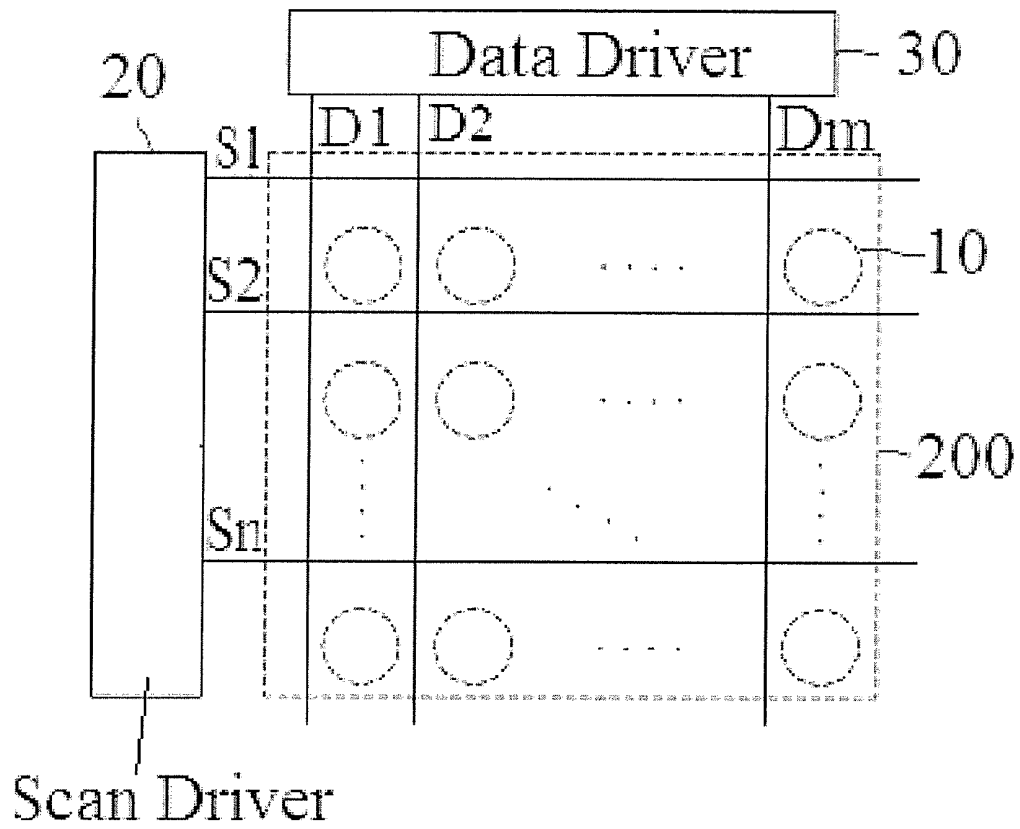


FIG. 4



ORGANIC LIGHT EMITTING DISPLAY APPARATUS

CROSS-REFERENCE TO RELATED PATENT APPLICATION

[0001] This application claims priority to and the benefit of Korean Patent Application No. 10-2008-0125962, filed on Dec. 11, 2008, in the Korean Intellectual Property Office, the entire content of which is incorporated herein by reference.

BACKGROUND OF THE INVENTION

[0002] 1. Field of the Invention

[0003] The present invention relates to an organic light emitting display apparatus, and more particularly, to an organic light emitting display apparatus having a touch panel function and a photo sensor with increased light sensitivity.

[0004] 2. Description of the Related Art

[0005] Developments in display technology have led to the replacement of conventional display devices with portable, thin flat panel display devices. Among the flat panel display devices, electroluminescent display devices, which are self-emissive display devices, have wide viewing angle, high contrast ratio, and high response speed, and thus have been considered as the next-generation display devices. In addition, an organic light-emitting display device having a light emitting layer formed of an organic material has improved properties in terms of brightness, driving voltage, and response speed in comparison to an inorganic light emitting display device, and can realize multiple colors.

[0006] Researches are in progress to develop organic light emitting display devices with touch panel functions. In one approach, a display screen having a touch panel function is mounted on an organic light emitting display apparatus so that a command can be input by touching the display screen with a finger or a pen device. The touch panel display screen used in this case includes a photo sensor.

[0007] However, in an organic light emitting display apparatus having a conventional touch panel function, light cannot be sensed properly when there is an inadequate amount of light due to dark surroundings. To address this problem, a method of sensing light using internal light emitted from an organic light emitting diode has been developed. In order to realize a touch panel function, the light emitted from the organic light emitting diode needs to be emitted to the outside of a panel and reflected by the finger of the user, and be incident on the photo sensor. However, some of the light rays emitted from the organic light emitting diode are not emitted to the outside of the panel and reflected by the finger of the user, but are directly incident on the photo sensor. Accordingly, the light sensitivity of the photo sensor is not totally reliable. So even when a user does not touch the display screen, internal light can still be sensed and malfunctions can occur, thereby increasing product defects and user's inconvenience.

SUMMARY OF THE INVENTION

[0008] An organic light emitting display apparatus according to an embodiment of the present invention includes a photo sensor with increased light sensitivity by preventing light from an organic light emitting diode from being directly incident on the photo sensor, wherein the organic light emit-

ting display apparatus includes a light blocking portion on a path of light emitted from the organic light emitting diode toward the photo sensor.

[0009] Exemplary embodiments according to the present invention provide an organic light emitting display apparatus including an organic light emitting diode, a photo sensor, and a light blocking portion, wherein the light blocking portion is at at least a side of the photo sensor so that light emitted from the organic light emitting diode is not directly incident on the photo sensor.

[0010] In one embodiment, the light blocking portion is on a path through which the light emitted from the organic light emitting diode would be directly incident on the photo sensor.

[0011] The organic light emitting display may further include a plurality of organic light emitting diodes and a plurality of photo sensors that are alternately arranged, and a plurality of light blocking portions, wherein one of the light blocking portions is between a respective one of the light emitting diodes and a respective one of the photo sensors.

[0012] According to one embodiment, an organic light emitting display apparatus includes at least one thin film transistor on a substrate. In an exemplary embodiment, the organic light emitting display apparatus includes a semiconductor active layer, a gate electrode that is insulated from the semiconductor active layer, and source and drain electrodes each contacting the semiconductor active layer; at least one photo sensor, each photo sensor at at least a side of a respective one of the at least one thin film transistor and detecting incident light thereon. In one embodiment, a plurality of pixel electrodes are provided on the at least one thin film transistor and a plurality of pixel definition layers. Each pixel definition layer is between the pixel electrodes. In another embodiment, a plurality of organic layers are provided on the pixel electrodes and the pixel definition layers, and a plurality of counter electrodes are provided on the organic layers and the pixel definition layers. In certain embodiments, a plurality of holes are provided in the pixel definition layers to expose respective plurality of organic layers.

[0013] In one embodiment, the counter electrodes are arranged along the plurality of holes of the pixel definition layers such that when light rays emit from the organic layers they would reflect on the counter electrodes. In another embodiment, each of the plurality of holes is arranged on a path through which light emitted from a respective one of the organic layers would be directly incident on the at least one photo sensor. In other words, each of the counter electrodes along the holes prevents light emitted from a respective one of the organic layers from being directly incident on the photo sensor.

[0014] In certain embodiments, the organic layers and the photo sensors are alternately arranged, and each of the plurality of holes is between a respective one of the organic layers and a respective one of the at least one photo sensor. In one embodiment, the organic layers surround the photo sensors, and the holes surround the photo sensors and are between the photo sensors and the organic layers.

[0015] In another embodiment, an organic light emitting display apparatus is provided. The organic light emitting display apparatus includes an organic light emitting diode, a photo sensor, and a light blocking portion, wherein the light blocking portion is at at least a side of the photo sensor so as to block light emitted from the organic light emitting diode from being directly incident on the photo sensor. The light

blocking portion is on a path through which the light emitted from the organic light emitting diode would be directly incident on the photo sensor.

BRIEF DESCRIPTION OF THE DRAWINGS

[0016] The above and other features and aspects of the present invention will become more apparent by describing in detail exemplary embodiments thereof with reference to the attached drawings in which:

[0017] FIG. 1 is a schematic cross-sectional view illustrating a portion of an organic light emitting display apparatus according to an embodiment of the present invention;

[0018] FIG. 2 is a schematic plan view illustrating the organic light emitting display apparatus of FIG. 1;

[0019] FIG. 3 is a cross-sectional view illustrating a portion of the organic light emitting display apparatus of FIG. 1; and

[0020] FIG. 4 is a schematic diagram of an organic light emitting display device including the organic light emitting display apparatus of FIGS. 1-3.

DETAILED DESCRIPTION

[0021] The present invention will now be described more fully with reference to the accompanying drawings, in which exemplary embodiments of the invention are shown.

[0022] FIG. 1 is a cross-sectional view illustrating a portion of an organic light emitting display apparatus according to an embodiment of the present invention, and FIG. 2 is a plan view illustrating the organic light emitting display apparatus of FIG. 1. In FIG. 2, an encapsulation substrate 300 illustrated in FIG. 1 is not shown.

[0023] Referring to FIGS. 1 and 2, a display unit 200 including an organic light emitting diode is placed on a substrate 100.

[0024] The substrate 100 may be formed of a transparent glass containing SiO₂ as a main component, but is not limited thereto, and thus may also be formed of a transparent plastic material that may be an insulating organic material selected from the group consisting of polyethersulphone (PES), polyacrylate (PAR), polyetherimide (PEI), polyethylene naphthalate (PEN), polyethylene terephthalate (PET), polyphenylene sulfide (PPS), polyallylate, polyimide, polycarbonate (PC), triacetate cellulose (TAC), cellulose acetate propionate (CAP), and combinations thereof.

[0025] In a bottom emission type organic light-emitting display apparatus in which an image is formed (i.e., displayed) toward the substrate 100, the substrate 100 is preferably formed of a transparent material. However, in a top emission type organic light-emitting display apparatus in which an image is formed (i.e., displayed) away from the substrate 100, the substrate 100 may not necessarily be a transparent material, and, in this case, the substrate 100 may be formed of a metal. When the substrate 100 is formed of a metal, the substrate 100 may include at least one material selected from the group consisting of carbon (C), iron (Fe), chromium (Cr), manganese (Mg), nickel (Ni), titanium (Ti), molybdenum (Mo), stainless steel (SUS), Invar alloys, Inconel alloys, Kovar alloys, and combinations thereof. However, the present invention is not limited to the above examples. Thus the substrate 100 may also be formed of a metal foil.

[0026] In one embodiment, a buffer layer of a bottom emission type organic light-emitting display apparatus may be formed on a top surface of the substrate 100 to planarize the

substrate 100 and to prevent penetration of impurities into the bottom emission type organic light-emitting display apparatus.

[0027] The substrate 100 including the display unit 200 is attached to an encapsulation substrate 300 that is disposed above the display unit 200. The encapsulation substrate 300 may be formed not only of a glass material but also of various plastic materials such as acrylic, or a metal.

[0028] The substrate 100 and the encapsulation substrate 300 are attached to each other using a sealant 410. The sealant 410 may be a sealing glass frit, as generally used in the art. Alternatively, the sealant 410 may be an organic sealant, an inorganic sealant, an organic/inorganic hybrid sealant, or a mixture thereof.

[0029] FIG. 3 is a cross-sectional view illustrating a portion of the organic light emitting display apparatus of FIG. 1, showing the display unit 200 in detail.

[0030] The display unit 200 will be briefly described hereinafter.

[0031] The display unit 200 is formed on the substrate 100, and includes an organic light emitting diode 230 and a photo sensor 240 formed on the substrate 100. Various modifications such as a thin film transistor 220, which controls light emission of the organic light emitting diode 230 and which is formed on the substrate 100 are possible, as illustrated in FIG. 3. Hereinafter, the display unit 200 having the structure illustrated in FIG. 3 will be described.

[0032] Referring to FIGS. 3 and 4, a plurality of thin film transistors 220 and a plurality of photo sensors 240 are formed on the substrate 100. Also, an organic light emitting diode 230 is formed above the thin film transistors 220 and the photo sensors 240. The organic light emitting diodes 230 includes a pixel electrode 231 that is electrically connected to the thin film transistor 220, a counter electrode 235 disposed over the entire substrate 100, and an intermediate layer 233 that is formed between the pixel electrode 231 and the counter electrode 235 and includes at least a light emitting layer.

[0033] The thin film transistors 220, each including a gate electrode 221, source and drain electrodes 223, a semiconductor layer 227, a gate insulating layer 213, and an interlayer insulating layer 215, are formed on the substrate 100. The present embodiment is not limited to the thin film transistors 220 of FIG. 3, and thus other various thin film transistors such as an organic thin film transistor including a semiconductor layer 227 formed of an organic material or a silicon thin film transistor formed of silicon may also be used. A buffer layer 211 formed of a silicon oxide or a silicon nitride may be further formed between the thin film transistors 220 and the substrate 100 according to necessity.

[0034] Photo sensors 240 are formed on the substrate 100. The photo sensors 240 may have various structures; for example, the photo sensor 240 as illustrated in FIG. 3 has a structure similar to a thin film transistor. The photo sensor 240 includes two metal layers 243 and a semiconductor layer 247, and when light is incident thereon, an electrical signal is generated between the two metal layers 243 via the semiconductor layer 247.

[0035] A passivation layer or a planarization layer 217 is formed to cover the thin film transistors 220 and the photo sensors 240, and a pixel definition layer (PDL) 219 defining regions of the pixels is formed on the passivation layer or planarization layer 217, and the organic light emitting diode 230 is formed on the PDL 219. The organic light emitting diode 230 includes the pixel electrode 231 and the counter

electrode **235** facing each other, and the intermediate layer **233** interposed between the pixel electrode **231** and the counter electrode **235** and formed of an organic material and interposed therebetween. The intermediate layer **233**, including at least a light emitting layer, may also include a plurality of layers as will be described later.

[0036] The pixel electrode **231** functions as an anode and the counter electrode **235** functions as a cathode electrode, or vice versa.

[0037] The pixel electrode **231** may be formed as a transparent electrode or a reflective electrode. When formed as a transparent electrode, the pixel electrode **231** may be formed of indium tin oxide (ITO), indium zinc oxide (IZO), ZnO, or In₂O₃. When formed as a reflective electrode, the pixel electrode **231** may include a reflection layer formed of Ag, Mg, Al, Pt, Pd, Au, Ni, Nd, Ir, Cr, or a compound thereof, and a layer formed of ITO, IZO, ZnO, or In₂O₃, formed on the reflection layer. However, the pixel electrode **231** is not limited thereto, and may be formed of various other materials. The structure of the pixel electrode **231** may also be a single layer or a multi-layer.

[0038] The counter electrode **235** may also be formed as a transparent electrode or a reflective electrode. When formed as a transparent electrode, the counter electrode **235** may include a layer in which Li, Ca, LiF/Ca, LiF/Al, Al, Mg, or a compound thereof is deposited toward the intermediate layer **233** between the pixel electrode **231** and the counter electrode **235**, and may also include a bus electrode line or an auxiliary electrode formed of ITO, IZO, ZnO, or In₂O₃. When formed of a reflective electrode, the counter electrode **235** may be formed by depositing Li, Ca, LiF/Ca, LiF/Al, Al, Mg or a compound thereof. However, the structure and materials of the counter electrode **235** are not limited thereto, and may be formed in other manners.

[0039] In one embodiment, the PDL **219** is formed to cover an edge (i.e., peripheral portion) of the pixel electrode **231**, and has a predetermined thickness. In addition to defining a light emitting region, the PDL **219** increases a distance (or gap) between the edge of the pixel electrode **231** and the counter electrode **235** to correspond to the thickness of the PDL **219**, to prevent a concentration of electric field on the edge portion of the pixel electrode **231**, thereby preventing a short circuit between the pixel electrode **231** and the counter electrode **235**. In addition, the PDL **219** prevents light emitted from the intermediate layer **233** from being directly incident on the photo sensor **240**.

[0040] Various kinds of the intermediate layer **233** including at least a light emitting layer may be formed between the pixel electrode **231** and the counter electrode **235**. In one embodiment, the intermediate layer **233** is formed of a small molecule organic material or a polymer organic material.

[0041] When formed of a small molecule organic material, the intermediate layer **233** may have a single-layer or multiple-layer structure in which a hole injection layer (HIL), a hole transport layer (HTL), an organic light emission layer (EML), an electron transport layer (ETL), and an electron injection layer (EIL) are stacked. Nonlimiting examples of suitable organic materials include copper phthalocyanine (CuPc), N,N'-Di(naphthalene-1-yl)-N,N'-diphenyl-benzidine (NPB), and tris-8-hydroxyquinoline aluminum (Alq₃). The small molecule organic materials may be formed using a vacuum deposition method using masks.

[0042] When formed of a polymer organic material, the intermediate layer **233** may have a structure formed of an

HTL and an EML. The HTL may be formed of poly(3,4-ethylenedioxythiophene) (PEDOT), and the EML may be formed of poly-phenylenevinylene (PPV) and polyfluorene.

[0043] The organic light emitting diode **230** is electrically connected to the thin film transistor **220** that is disposed therebelow. When the planarization layer **217** covering the thin film transistor **220** is formed, the organic light emitting diode **230** is disposed on the planarization layer **217**, and the pixel electrode **231** of the organic light emitting diode **230** is electrically connected to the thin film transistor **220** via a contact hole formed in the planarization layer **217**.

[0044] The organic light emitting diode **230** formed on the substrate **100** is sealed by the encapsulation substrate **300**. The encapsulation substrate **300** may be formed of various materials such as glass or plastic, as described above.

[0045] Thus, in the above-described organic light emitting display apparatus according to an embodiment of the present invention, a light blocking portion is formed so that light emitted from the intermediate layer **233** is not directly incident on the photo sensor **240**.

[0046] In an organic light emitting display apparatus with a conventional touch panel function, it is difficult to efficiently or properly perform light sensing when there is an inadequate amount of light due to the dark surroundings. To address this problem, methods of sensing light using internal light that is emitted from an organic light emitting diode have been developed. However, some of light rays emitted from the organic light emitting diode are not only emitted to the outside of the organic light emitting display apparatus and reflected by a finger of the user and incident again on the photo sensor, but are also directly incident on the photo sensor. Consequently, light sensing function of the photo sensor is not totally accurate. Thus, even when a user does not touch the display screen, internal light may be sensed and malfunctions can occur, thereby increasing product defects and users' inconvenience.

[0047] In order to address this problem, in the organic light emitting display apparatus according to the current embodiment of the present invention, a hole **219a** is formed in the PDL **219** and the counter electrode **235** is formed along the hole **219a** so as to function as a light blocking portion so that light emitted from the intermediate layer **233** is not directly incident on the photo sensor **240**.

[0048] The semiconductor layer **247** is formed on the substrate **100**. The gate insulating layer **213** and the interlayer insulating layer **215** are sequentially stacked on the semiconductor layer **247**, and a contact hole is formed in the gate insulating layer **213** and the interlayer insulating layer **215**, and the metal layers **243** are formed in the contact hole. The passivation layer or planarization layer **217** is disposed to cover the metal layers **243**. In turn, the PDL **219** defining regions of each pixel is formed on the passivation layer or planarization layer **217**, and the organic light emitting diode **230** is disposed on the PDL **219**.

[0049] The hole **219a** is formed in the PDL **219**. That is, there is a hole in a portion of the PDL **219** on a path through which light emitted from the intermediate layer **233** is directly incident on the photo sensor **240**. The pixel electrode **231**, the intermediate layer **233**, and the counter electrode **235** are sequentially formed on the PDL **219**. The counter electrode **235** is formed over the PDL **219** and covers the PDL **219** entirely, and thus the counter electrode **235** is also formed along the hole **219a** in the PDL **219**. The counter electrode

235 in the portion of the hole **219a** of the PDL **219** is curved, and a curved portion of the counter electrode **235** functions as a light blocking portion **235a**.

[0050] The hole **219a** and the light blocking portion **235a** in the hole **219a** are formed on the path of light that is directly incident from the intermediate layer **233** on the photo sensor **240**. In other words, the hole **219a** and the light blocking portion **235a** in the hole **219a** are formed at least at one side of the photo sensor **240**. Also, the hole **219a** and the light blocking portion **235a** in the hole **219a** are formed between the thin film transistors **220** and the photo sensors **240**.

[0051] In FIG. 3, reference numeral **L1** denotes a normal path of light, where light sensing takes place based on internal light emitted from the organic light emitting diode **230**. That is, some of the light emitted from the intermediate layer **233** is emitted to the outside of the display unit **200** and is reflected by the finger **f** of the user and is incident on the photo sensor **240**, thereby causing the photo sensor **240** to sense light. Reference numeral **L2** denotes a non-typical path of internal light rays emitted from the organic light emitting diode **230**. That is, some of the light rays emitted from the intermediate layer **233** are directly incident on the photo sensor **240**. In order to address such problem, a light blocking portion is mounted on a path of light that would otherwise be directly incident on the photo sensor **240** from the intermediate layer **233**, thereby preventing light emitted from the intermediate layer **233** from being directly incident on the photo sensor **240**.

[0052] FIG. 4 is a schematic diagram of an organic light emitting display device including the organic light emitting display apparatus of FIGS. 1-3 or any other suitable organic light emitting display apparatus.

[0053] As shown, the organic light emitting display device according to one exemplary embodiment of the present invention includes an organic light emitting display panel **200**, a scan driver **20**, and a data driver **30**.

[0054] The organic light emitting display panel **200** includes a plurality of data lines **D1** to **Dm** arranged in columns, a plurality of scan lines **S1** to **Sn** arranged in rows, and a plurality of pixel circuits **10**. The data lines **D1** to **Dm** transmit a data voltage representing an image signal to the pixel circuits **10**. The scan lines **S1** to **Sn** transmit a select signal for selecting a pixel circuit to the pixel circuits **10**. Each pixel circuit **10** is formed in a pixel area defined by two adjacent data lines **D1** to **Dm** and two adjacent scan lines **S1** to **Sn**. Each of the pixel circuits **10** includes an organic light emitting diode **230**, a photo sensor **240**, and a light blocking portion **235a**.

[0055] The scan driver **20** sequentially applies the select signal to the scan lines **S1** to **Sn**, and the data driver **30** applies the data voltage representing an image signal to the data lines **D1** to **Dm**.

[0056] The scan driver **20** and/or the data driver **30** can be coupled to the display panel **200**, or mounted in the form of a chip on a tape carrier package (TCP) that is coupled to the display panel **200** by soldering. The scan driver **20** and/or the data driver **30** can also be mounted in the form of a chip on a flexible printed circuit (FPC) or a film coupled to the display panel by soldering. Alternatively, the scan driver **20** and/or the data driver **30** can be mounted directly on the glass substrate of the display panel, or replaced by the driving circuit comprised of the same layers as scan and data lines and thin film transistors on the glass substrate.

[0057] According to an embodiment of the present invention, the light emitted from the organic light emitting diode **230** is prevented from being directly incident on the photo sensor **240**, thereby increasing the light sensitivity and decreasing malfunction of products and product defects. Accordingly, convenience of the user is increased.

[0058] While the present invention has been particularly shown and described with reference to exemplary embodiments thereof, it will be understood by those of ordinary skill in the art that various changes in form and details may be made therein without departing from the spirit and scope of the present invention, as defined by the following claims and their equivalents.

What is claimed is:

1. An organic light emitting display apparatus comprising: an organic light emitting diode, a photo sensor, and a light blocking portion, wherein the light blocking portion is at least a side of the photo sensor so that light emitted from the organic light emitting diode is not directly incident on the photo sensor.
2. The organic light emitting display apparatus of claim 1, wherein the light blocking portion is on a path through which the light emitted from the organic light emitting diode would be directly incident on the photo sensor.
3. The organic light emitting display apparatus of claim 1, further comprising a plurality of organic light emitting diodes and a plurality of photo sensors that are alternately arranged, and a plurality of light blocking portions, wherein one of the light blocking portions is between a respective one of the light emitting diodes and a respective one of the photo sensors.
4. An organic light emitting display apparatus comprising: at least one thin film transistor on a substrate and comprising a semiconductor active layer, a gate electrode that is insulated from the semiconductor active layer, and source and drain electrodes each contacting the semiconductor active layer; at least one photo sensor, each photo sensor at at least a side of a respective one of the at least one thin film transistor and for detecting incident light thereon; a plurality of pixel electrodes on the at least one thin film transistor and a plurality of pixel definition layers, each pixel definition layer between respective ones of the pixel electrodes; a plurality of organic layers on the pixel electrodes and the pixel definition layers; and a plurality of counter electrodes on the organic layers and the pixel definition layers, wherein a plurality of holes are in the pixel definition layers to expose respective said plurality of organic layers.
5. The organic light emitting display apparatus of claim 4, wherein the counter electrodes are along the plurality of holes of the pixel definition layers.
6. The organic light emitting display apparatus of claim 5, wherein some of light rays emitted from the organic layers are reflected on the counter electrodes along the plurality of holes of the pixel definition layers.
7. The organic light emitting display apparatus of claim 4, wherein each of the plurality of holes is arranged on a path through which light emitted from a respective one of the organic layers would be directly incident on the at least one photo sensor.

8. The organic light emitting display apparatus of claim **7**, wherein each of the counter electrodes along the holes prevents light emitted from a respective one of the organic layers from being directly incident on the photo sensor.

9. The organic light emitting display apparatus of claim **4**, wherein the organic layers and the at least one photo sensor are alternately arranged, and each of the plurality of holes is between a respective one of the organic layers and a respective one of the at least one photo sensor.

10. The organic light emitting display apparatus of claim **4**, wherein the plurality of organic layers surround the photo sensors, and the plurality of holes surround the photo sensors and are between the photo sensors and the organic layers.

11. An organic light emitting display apparatus comprising:

an organic light emitting diode, a photo sensor, and a light blocking portion,

wherein the light blocking portion is at at least a side of the photo sensor so as to block light emitted from the organic light emitting diode from being directly incident on the photo sensor.

12. The organic light emitting display apparatus of claim **11**, wherein the light blocking portion is on a path through which the light emitted from the organic light emitting diode would be directly incident on the photo sensor.

13. The organic light emitting display apparatus of claim **11**, further comprising a plurality of organic light emitting diodes and a plurality of photo sensors that are alternately arranged, and a plurality of light blocking portions, wherein one of the light blocking portions is between a respective one of the light emitting diodes and a respective one of the photo sensors.

* * * * *

专利名称(译)	有机发光显示装置		
公开(公告)号	US20100148163A1	公开(公告)日	2010-06-17
申请号	US12/636303	申请日	2009-12-11
[标]申请(专利权)人(译)	IM KI JU 朴容SUNG 朴埗佑 金武金 尹韩姬 金光HAE DOH SUNG WON KIM KYOUNG BO KIM GUN植 OH JUN SIK		
申请(专利权)人(译)	IM KI-JU 朴容晟 朴埗佑 金武金 尹韩熙 金光HAE DOH SUNG-WON KIM KYOUNG-BO KIM GUN植 OH JUN-SIK		
当前申请(专利权)人(译)	IM KI-JU 朴容晟 朴埗佑 金武金 尹韩熙 金光HAE DOH SUNG-WON KIM KYOUNG-BO KIM GUN植 OH JUN-SIK		
[标]发明人	IM KI JU PARK YONG SUNG PARK YONG WOO KIM MOO JIN YOON HAN HEE KIM KWANG HAE DOH SUNG WON KIM KYOUNG BO KIM GUN SHIK OH JUN SIK		
发明人	IM, KI-JU PARK, YONG-SUNG PARK, YONG-WOO KIM, MOO-JIN YOON, HAN-HEE		

KIM, KWANG-HAE
DOH, SUNG-WON
KIM, KYOUNG-BO
KIM, GUN-SHIK
OH, JUN-SIK

IPC分类号	H01L51/50
CPC分类号	G06F3/0412 H01L27/3269 G06F3/042
优先权	1020080125962 2008-12-11 KR
其他公开文献	US8183562
外部链接	Espacenet USPTO

摘要(译)

有机发光显示装置包括有机发光二极管，光传感器和光阻挡部分。光阻挡部分位于光传感器的至少一侧，使得从有机发光二极管发射的光不直接入射在光传感器上。

